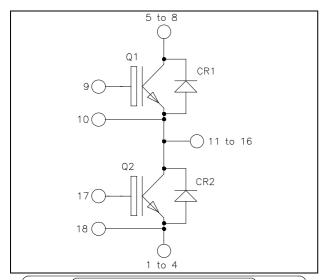
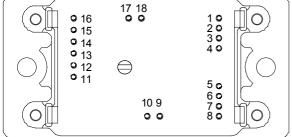


# Phase leg Fast Trench + Field Stop IGBT3 Power Module

 $V_{CES} = 1200V$  $I_C = 50A$  @ Tc = 80°C





Pins 1/2/3/4 ; 5/6/7/8 ; 11/12/13/14/15/16 must be shorted together

## Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

#### **Features**

- Fast Trench + Field Stop IGBT3 Technology
  - Low voltage drop
  - Low tail current
  - Switching frequency up to 20 kHz
  - Soft recovery parallel diodes
  - Low diode VF
  - Low leakage current
  - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
- High level of integration

#### **Benefits**

- Outstanding performance at high frequency operation
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive T<sub>C</sub> of V<sub>CEsat</sub>
- RoHS Compliant

## All ratings @ $T_i = 25^{\circ}C$ unless otherwise specified

#### **Absolute maximum ratings**

Symbol	Parameter		Max ratings	Unit
$V_{CES}$	Collector - Emitter Breakdown Voltage		1200	V
ī	Continuous Collector Current	$T_C = 25^{\circ}C$	75	
$I_{C}$	Continuous Conector Current	$T_C = 80$ °C	50	Α
$I_{CM}$	Pulsed Collector Current	$T_C = 25^{\circ}C$	100	
$V_{GE}$	Gate – Emitter Voltage		±20	V
$P_{D}$	Maximum Power Dissipation	$T_C = 25^{\circ}C$	277	W
RBSOA	Reverse Bias Safe Operating Area	$T_J = 125$ °C	100A @ 1150V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

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Electrical	Characteristics
Liccuitai	Character isues

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
$I_{CES}$	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$				50	μΑ
V <sub>CE(sat)</sub>	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25^{\circ}C$	1.4	1.7	2.1	V
		$I_C = 50A$	$T_{j} = 125^{\circ}C$		2.0		v
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$ , $I_C = 2mA$		5.0	5.8	6.5	V
$I_{GES}$	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA

**Dynamic Characteristics** 

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V, V_{CE} = 25V$			3600		pF
$C_{rss}$	Reverse Transfer Capacitance	f = 1MHz			160		PI
$Q_{G}$	Gate charge	$V_{GE}=\pm 15V, I_{C}=5$ $V_{CE}=600V$	50A		0.47		μС
$T_{d(on)}$	Turn-on Delay Time	Inductive Switch	ning (25°C)		90		ns
$T_{r}$	Rise Time	$V_{GE} = \pm 15V$			30		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 600 \text{V}$ $I_{\text{C}} = 50 \text{A}$			420		
$T_{\mathrm{f}}$	Fall Time	$R_G = 18\Omega$		70			
$T_{d(on)}$	Turn-on Delay Time	Inductive Switch	ning (125°C)		90		ns
$T_{r}$	Rise Time	$V_{GE} = \pm 15V$			50		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 600V$ $I_{\text{C}} = 50A$			520		
$T_{\mathrm{f}}$	Fall Time	$R_G = 18\Omega$			90		
Eon	Turn-on Switching Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 600V$	$V_{GE} = \pm 15V$ $T_{c} = 125^{\circ}C$		5		ano I
$E_{\text{off}}$	Turn-off Switching Energy	$I_{C} = 50A$ $R_{G} = 18\Omega$	$T_j = 125$ °C		5.5		mJ
$I_{sc}$	Short Circuit data	$V_{GE} \le 15V$ ; $V_{Bus} = 900V$ $t_p \le 10 \mu s$ ; $T_j = 125 ^{\circ}C$			200		A
$R_{thJC}$	Junction to Case Thermal Resistance	l Resistance				0.45	°C/W

**Reverse diode ratings and characteristics** 

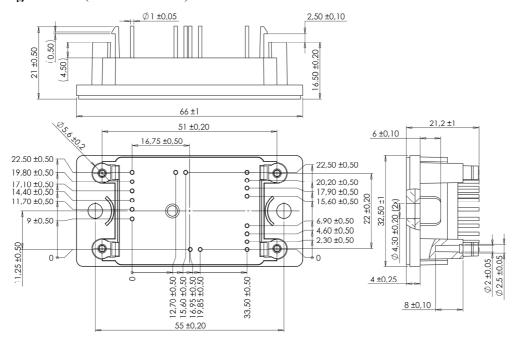
Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
$V_{RRM}$	Maximum Peak Repetitive Reverse Voltage		1200			V	
$I_{RM}$	Maximum Reverse Leakage Current	V <sub>R</sub> =1200V				50	μA
$I_F$	DC Forward Current		$Tc = 80^{\circ}C$		50		A
$V_{\mathrm{F}}$	Diode Forward Voltage	$I_F = 50A$	$T_i = 25^{\circ}C$		1.6	2.1	V
<b>*</b> F	Blode I of ward Voltage	1F 3071	$T_i = 125$ °C		1.6		
t <sub>rr</sub>	Reverse Recovery Time		$T_j = 25$ °C		170		ns μC
·rr		$I_F = 50A$ $V_R = 600V$ $di/dt = 1900A/\mu s$	$T_j = 125$ °C		280		
0	Reverse Recovery Charge		$T_j = 25^{\circ}C$		5.6		
Q <sub>rr</sub>			$T_{j} = 125^{\circ}C$		9.9		μС
$E_{r}$	Reverse Recovery Energy	·	$T_j = 25^{\circ}C$		2.2		mJ
$\mathbf{E}_{\mathrm{r}}$	Reverse Recovery Ellergy		$T_{j} = 125^{\circ}C$		4.1		1113
$R_{thJC}$	Junction to Case Thermal Resistance					0.72	°C/W



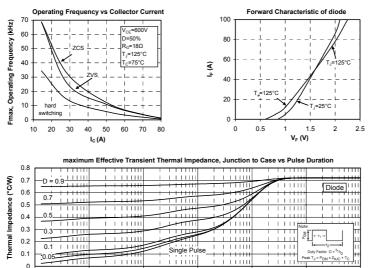
## Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000			V
$T_{J}$	Operating junction temperature range			-40		150	
$T_{STG}$	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M4	2		3	N.m
Wt	Package Weight				75	g	

## SP2 Package outline (dimensions in mm)



## **Typical Performance Curve**



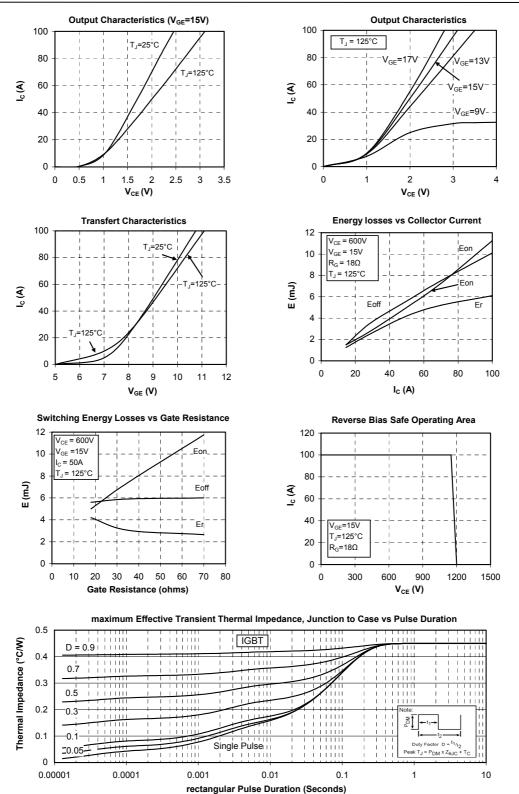
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0.001 0.01 0.1
rectangular Pulse Duration (Seconds)

0.00001

0.0001







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